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# HIGH DENSITY RECORDING MEDIUM WITH SUPER-RESOLUTION NEAR-FIELD STRUCTURE MANUFACTURED USING HIGH-MELTING POINT METAL OXIDE OR SILICON OXIDE MASK LAYER

# 5 Technical Field

The present invention relates to a high density recording medium, and more particularly, to a high density recording medium with a super-resolution near-field structure that is manufactured using a high-melting point metal oxide or silicon oxide mask layer.

# 10 Background Art

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Conventional recording media can be classified into magneto-optical recording media or phase change recording media. In magneto-optical recording media, such as mini disks (MDs), information is read by detecting the rotation of a straight polarized light reflected from a magnetic film according to the magnetic force and the magnetization direction of the magnetic film. The rotation of the reflected light is known as the "Kerr Effect". In phase change recording media, such as digital versatile discs (DVDs), information is read based on the difference in reflectivity due to the different absorption coefficients of an optical constant between an amorphous recorded domain and a crystalline non-recorded domain of the recording medium.

Recently, many diversified methods of recording information using micro marks (pits), as in a phase change method, and reproducing information from the recording medium regardless of the diffraction limit have been suggested. The most interested one among these methods is a recording method using a super-resolution near-field structure, which is disclosed in Applied Physics Letters, Vol. 73, No.15, Oct. 1998, and Japanese Journal of Applied Physics, Vol. 39, Part I, No.2B, 2000, pp. 980- 981. A super-resolution near-field structure utilizes local surface plasmons generated in its special mask layer to reproduce information. The super-resolution near-field structure is classified as an antimony

(Sb) transmission type which has an antimony mask layer that becomes transparent by laser irradiation when reproducing information from the recording medium or as a silver oxide decomposition type which has a silver oxide (AgO<sub>x</sub>) mask layer that decomposes into oxygen and silver, which acts as a scattering source inducing local plasmons.

FIG. 1 illustrates the structure of a recording medium using a conventional super-resolution near-field structure.

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As shown in FIG. 1, the recording medium includes a second dielectric layer 112-2 made of, for example, ZnS-SiO<sub>2</sub>, a recording layer 115 made of, for example, GeSbTe, a protective layer 114 made of dielectric materials, for example, ZnS-SiO<sub>2</sub> or SiN, a mask layer 113 made of, for example, Sb or AgO<sub>x</sub>, a first dielectric layer 112-1 made of, for example, ZnS-SiO<sub>2</sub> or SiN, and a transparent polycarbonate layer 111, which are sequentially stacked upon one another.

When the mask layer 113 is made of Sb, SiN is used for the protective layer 114 and the first dielectric layer 112-1. When the mask layer 113 is made of AgO<sub>x</sub>, ZnS-SiO<sub>2</sub> is used for the protective layer 114 and the first dielectric layer 112-1. The protective layer 114 prevents reaction between the recording layer 115 and the mask layer 113 and is a site upon which a near field acts when reproducing information. When reproducing information, Sb of the mask layer 113 becomes transparent, and AgO<sub>x</sub> of the mask layer 113 decomposes into oxygen and silver, which acts as a scattering source inducing local plasmons.

The recording medium is irradiated with a laser beam of about 10-15 mW emitted from a laser source 118 through a focusing lens (not shown) to heat the recording layer 115 above 600°C so that a laser-irradiated domain of the recording layer 115 becomes amorphous and has a smaller absorption coefficient k of an optical constant (n,k), regardless of the change of refractive index n of the optical constant (n,k). In an irradiated domain of the Sb or AgO<sub>x</sub> mask layer 113, the crystalline structure of Sb changes or AgO<sub>x</sub> irreversibly decomposes,

thereby acting as a scattering source which generates plasmons with the result that light of a shorter wavelength than the radiated laser beam is generated. The protective layer 114 serves as a super-resolution near-field toward the recording layer 115. As a result, it is possible to reproduce information recorded on the recording medium as micro marks which are smaller in size than a diffraction limit of the laser used. Therefore, it becomes possible to reproduce information recorded in a high density recording medium using such a super-resolution near-field structure regardless of a diffraction limit of the laser used.

However, in recording media having such a super-resolution near-field structure, their mask layer and recording layer have similar transition temperatures, so ensuring thermal stability during information reproduction is considered as being important. Furthermore, such a super-resolution near-field structure results in poor noise characteristics.

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#### Disclosure of the Invention

The present invention provides a high density recording medium with a super-resolution near-field structure that ensures improved thermal stability and noise characteristics during information reproduction therefrom, by adopting a mask layer comprising a high-melting point metal oxide or silicon oxide.

In accordance with an aspect of the present invention, there is provided a high density recording medium with a super-resolution near-field structure including a sequential stack of a second dielectric layer, a recording layer, a protective layer, a mask layer, a first dielectric layer, and a polycarbonate layer, wherein the mask layer comprises high melting point metal oxide or silicon oxide to generate a near field by optically or thermally inducing physical changes in the crystalline structure and optical properties of the high melting point metal oxide or silicon oxide.

A super-resolution near-field high density recording medium according to the present invention that offers effective thermal stability

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and improved noise characteristics during reproduction may be realized with the mask layer comprising high melting point metal oxide or silicon oxide.

A super-resolution near-field high density recording medium according to the present invention that offers effective thermal stability and improved noise characteristics during reproduction may be realized with a mask layer comprising WO<sub>x</sub> as a high melting point metal oxide showing reversible physical changes.

A super-resolution near-field high density recording medium according to the present invention that offers effective thermal stability and improved noise characteristics during reproduction may be realized with a mask layer comprising TaO<sub>x</sub> or AuO<sub>x</sub> as a high melting point metal oxide showing irreversible physical changes.

A super-resolution near-field high density recording medium according to the present invention that offers effective thermal stability during reproduction may be realized with a mask layer comprising  $\mathrm{SiO}_x$  as a silicon oxide showing irreversible physical changes.

A super-resolution near-field high density recording medium that offers effective thermal stability and improved noise characteristics during reproduction may further include a reflective layer comprising silver (Ag) or aluminum (Al) below the second dielectric layer.

# Brief Description of the Drawings

- FIG. 1 illustrates a high density recording medium with a conventional super-resolution near-field structure;
- FIG. 2 illustrates a high density recording medium with a super-resolution near-field structure according to an embodiment of the present invention;
- FIG. 3 is a gram of carrier to noise ratio (CNR) versus mark length, for the recording medium according to the present invention and the conventional one; and
  - FIG. 4 is a graph of noise level versus mark length, for the

recording medium according to the present invention and the conventional one.

# Best mode for carrying out the Invention

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The structure and operation of the present invention for resolving the conventional problems will be described below in detail with frequent reference to the appended drawings.

FIG. 2 illustrates a high density recording medium with a super-resolution near-field structure according to an embodiment of the present invention. The high density recording medium of FIG. 2 includes a reflective layer made of silver (Ag) or aluminum (Al), a second dielectric layer 122-2 made of, for example, ZnS-SiO<sub>2</sub>, a recording layer 125 made of, for example, GeSbTe, a protective layer 124 made of a dielectric material, for example, ZnS-SiO<sub>2</sub>/SiN, a mask layer 123, a first dielectric layer 122-1 made of, for example, ZnS-SiO<sub>2</sub>/SiN, and a transparent polycarbonate layer 121, which are sequentially stacked upon one another.

The mask layer 123 is made of one of high-melting point metal oxide and silicon oxide. Examples of high-melting point metal oxide includes WO<sub>x</sub> which shows nearly reversible physical changes for improving thermal stability and noise characteristics during reproduction from the recording medium and TaO<sub>x</sub> or AuO<sub>x</sub> which exhibits irreversible physical changes and effectively improves noise characteristics. An example of silicon oxide is SiO<sub>x</sub> which leads to irreversible physical changes and effectively improves noise characteristics.

The protective layer 124 prevents reactions between the recording layer 125 and the mask layer 123 and serves as a site where a super-resolution near-field acts upon during reproducing information. In addition, the mask layer 123 acts as a scattering source for generating local plasmons through its physical changes in crystalline structure and optical properties.

The reflective layer 128 made of Ag or Al is for inducing physical

changes in the crystalline structure and optical properties of the recording layer 125 which faces away from the incident laser beam side and the second dielectric layer 122-2 to occur nearly as much as those of the upper portion of the recording layer 125 which faces the incident laser beam side and the first dielectric layer 122-1.

Hereinafter, the mask layer 124 is described as being made of  $WO_x$  which shows nearly reversible physical changes.

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When the recording medium is irradiated through a focusing lens (not shown) with a laser beam having a wavelength of about 405 nm emitted from a laser source (not shown) with a power of about 11 mW to heat the recording medium 125 above 600°C, the laser irradiated domain of the recording medium becomes amorphous and have a reduced absorption coefficient k of an optical constant (n,k), regardless of the change of refractive index n. In the laser irradiated domain of the  $WO_{\kappa}$ mask layer, plasmons are generated due to the physical changes in its crystalline structure and optical properties, which occur as a result of the reversible reaction, expressed by  $4WO_3 = 2W_2O_5 + O_2$ , in the  $WO_x$  mask layer, so that light having a shorter wavelength than the initially radiated laser beam is emitted. In addition, the protective layer 124 serves as a super-resolution near-field toward the recording layer 125. As a result, it is possible to reproduce information recorded on the recording medium as micro marks which are smaller in size than a diffraction limit of the laser used. Therefore, it becomes possible to reproduce information recorded in a high density recording medium using such a super-resolution near-field structure regardless of a diffraction limit of the laser used.

FIG. 3 is a graph of carrier to noise ratio (CNR) versus mark length, for high-density recording media with a super-resolution near-field structure according to the present invention and conventional one. For both the high-density recording media, a 405-nm laser beam was radiated at a power of 11 mW through a lens having a numerical

aperture (NA) of 0.65 at a rate of 3 m/sec to record data, and the same laser beam but at a power of 4 mW was radiated under the same conditions as for the recording, to reproduce data. Referring to the results in FIG. 3, the resolution limit mark length at a CNR of 40 dB is 155.8 nm for the conventional super-resolution near-field high density recording medium with a AgO<sub>x</sub> mask layer and 130 nm for the super-resolution near-field high density recording medium with the WO<sub>x</sub> mask layer according to the present invention. This result indicates that higher density recording can be achieved with the super-resolution near-field high density recording medium according to the present invention than the conventional one under the same conditions.

FIG. 4 is a graph of noise level versus mark length, for the super-resolution near-field high density recording medium according to the present invention and the conventional one. The results of FIG. 4 were obtained as a result of experimentations under the same conditions as for the results of FIG. 3. As is apparent from FIG. 4, the noise level of the conventional super-resolution near-field high density recording medium with the AgO<sub>x</sub> mask layer is –65 dBm, and the noise level of the super-resolution near-field high density recording medium with the WO<sub>x</sub> mask layer according to the present invention is –76 dBm. This result indicates that the super-resolution near-field high density recording medium according to the present invention offers more effective noise characteristics than the conventional one.

# 25 Industrial Applicability

With a super-resolution near-field high density recording medium having a high melting point metal oxide or silicon oxide mask layer according to the present invention, thermal stability and noise characteristics during reproduction are improved.

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